Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

3.625 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 1.218 inches and 1.250 inches

Thread Size:

0.750 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

3.0 gate trigger voltage, dc and 0.3 gate non-trigger voltage, dc and 400.0 nonrepetitive peak reverse voltage

Current Rating Per Characteristic:

200.00 milliamperes forward current, total rms preset

Power Rating Per Characteristic:

10.0 watts small-signal input power, common-collector blank

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnpn

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 uninsulated wire lead w/terminal lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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